SHORT COMMUNICATION



Solar cell efficiency tables (version 62)

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Abstract

Consolidated tables showing an extensive listing of the highest independently confirmed efficiencies for solar cells and modules are presented. Guidelines for inclusion of results into these tables are outlined, and new entries since January 2023 are reviewed.

KEYWORDS

energy conversion efficiency, photovoltaic efficiency, solar cell efficiency

1 | INTRODUCTION

Since January 1993, 'Progress in Photovoltaics' has published six monthly listings of the highest confirmed efficiencies for a range of photovoltaic cell and module technologies. ¹⁻³ By providing guidelines for the inclusion of results into these tables, this not only provides an authoritative summary of the current state-of-the-art but also encourages researchers to seek independent confirmation of results and to

report results on a standardised basis. In version 33 of these tables,³ results were updated to the new internationally accepted reference spectrum (International Electrotechnical Commission IEC 60904-3, Ed. 2, 2008).

The most important criterion for the inclusion of results into the tables is that they must have been independently measured by a recognised test centre listed elsewhere¹ (an additional test centre listed in Appendix A). A distinction is made between three different

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TABLE 1 Confirmed single-junction terrestrial cell and submodule efficiencies measured under the global AM1.5 spectrum (1000 W/m²) at 25°C (IEC 60904-3: 2008 or ASTM G-173-03 global).

Classification	Efficiency (%)	Area (cm²)	V _{oc} (V)	J _{sc} (mA/cm ²)	Fill factor (%)	Test centre (date)	Description
Silicon	, , ,						·
Si (crystalline cell)	26.8 ± 0.4^{a}	274.4 (t)	0.7514	41.45 ^b	86.1	ISFH (10/22)	LONGi, n-type HJT ⁴
Si (DS wafer cell)	24.4 ± 0.3 ^a	267.5 (t)	0.7132	41.47 ^c	82.5	ISFH (8/20)	Jinko Solar, n-type
Si (thin transfer submodule)	21.2 ± 0.4	239.7 (ap)	0.687 ^e	38.50 ^{d,e}	80.3	NREL (4/14)	Solexel (35 μm thick) ⁵
Si (thin-film minimodule)	10.5 ± 0.3	94.0 (ap)	0.492 ^e	29.7 ^{d,f}	72.1	FhG-ISE (8/07)	CSG Solar (<2 µm on glass) ⁶
III-V cells							
GaAs (thin-film cell)	29.1 ± 0.6	0.998 (ap)	1.1272	29.78 ^g	86.7	FhG-ISE (10/18)	Alta Devices ⁷
GaAs (multicrystalline)	18.4 ± 0.5	4.011 (t)	0.994	23.2	79.7	NREL (11/95)	RTI, Ge substrate ⁸
InP (crystalline cell)	24.2 ± 0.5 ^h	1.008 (ap)	0.939	31.15 ⁱ	82.6	NREL (3/13)	NREL ⁹
Thin-film chalcogenide							
CIGS (cell) (Cd-free)	23.35 ± 0.5	1.043 (da)	0.734	39.58 ^j	80.4	AIST (11/18)	Solar Frontier ¹⁰
CIGSSe (submodule)	20.3 ± 0.4	526.7 (ap)	0.6834	39.55 ^{dk}	75.1	NREL (5/23)	Avancis, 100 cells ¹¹
CdTe (cell)	21.0 ± 0.4	1.0623 (ap)	0.8759	30.25 ^e	79.4	Newport (8/14)	First Solar, on glass ¹²
CZTSSe (cell)	12.1 ± 0.3	1.066 (da)	0.5379	35.29 ^k	63.6	NPVM (4/23)	IoP/CAS ¹³
CZTS (cell)	10.0 ± 0.2	1.113 (da)	0.7083	21.77 ⁱ	65.1	NREL (3/17)	UNSW ¹⁴
Amorphous/microcrystalline							
Si (amorphous cell)	10.2 ± 0.3 ^{L,h}	1.001 (da)	0.896	16.36 ^e	69.8	AIST (7/14)	AIST ¹⁵
Si (microcrystalline cell)	11.9 ± 0.3 ^h	1.044 (da)	0.550	29.72 ⁱ	75.0	AIST (2/17)	AIST ¹⁶
Perovskite							
Perovskite (cell)	24.35 ± 0.5^{m}	1.007 (da)	1.159	25.60 ^k	82.1	NPVM (4/23)	NUS/SERIS ¹⁷
Perovskite (minimodule)	22.4 ± 0.5 ^m	26.02 (da)	1.127 ^d	25.61 ^{d,b}	77.6	NPVM (7/22)	EPFLSion/NCEPU, 8 cells ¹⁸
Dye sensitised							
Dye (cell)	11.9 ± 0.4 ⁿ	1.005 (da)	0.744	22.47°	71.2	AIST (9/12)	Sharp ^{19,20}
Dye (minimodule)	10.7 ± 0.4 ⁿ	26.55 (da)	0.754 ^d	20.19 ^{d,p}	69.9	AIST (2/15)	Sharp, 7 serial cells ^{19,20}
Dye (submodule)	8.8 ± 0.3^{n}	398.8 (da)	0.697 ^d	18.42 ^{d,q}	68.7	AIST (9/12)	Sharp, 26 serial cells ^{19,20}
Organic							
Organic (cell)	$15.2 \pm 0.2^{h,r}$	1.015 (da)	0.8467	24.24 ^c	74.3	FhG-ISE (10/20)	Fraunhofer ISE ²¹
Organic (minimodule)	15.7 ± 0.3 ^r	19.31 (da)	0.8771 ^d	24.37 ^{el}	73.4	JET (1/23)	ZhejiangU, 7 cells ²²
Organic (submodule)	11.7 ± 0.2 ^r	203.98 (da)	0.8177 ^d	20.68 ^{d,s}	69.3	FhG-ISE (10/19)	ZAE Bayern, 33 cells ²³

Abbreviations: (ap), aperture area; (da), designated illumination area; (t), total area; AIST; Japanese National Institute of Advanced Industrial Science and Technology; a-Si, amorphous silicon/hydrogen alloy; CIGS, $Culn_{1-y}Ga_ySe_2$; CZTS, Cu_2ZnSnS_4 ; CZTSSe, $Cu_2ZnSnS_{4-y}Se_y$; DS, directionally solidified (including mono cast and multicrystalline); FhG-ISE, Fraunhofer Institut für Solare Energiesysteme; nc-Si, nanocrystalline or microcrystalline silicon.

^aContacting: Front: 9BB, busbar resistance neglecting; Rear: 9BB, full area contacting, highly reflective chuck.

^bSpectral response and current-voltage curve reported in version 61 of these tables.

^cSpectral response and current-voltage curve reported in version 57 of these tables.

^dReported on a 'per cell' basis.

^eSpectral responses and current-voltage curve reported in version 45 of these tables.

^fRecalibrated from original measurement.

gSpectral response and current-voltage curve reported in version 53 of these tables.

^hNot measured at an external laboratory.

ⁱSpectral response and current-voltage curve reported in version 50 of these tables.

^jSpectral response and current-voltage curve reported in version 54 of these tables.

^kSpectral response and current-voltage curve reported in the present version of these tables.

 $^{^{\}rm I}\!S$ tabilised by 1000-h exposure to 1 sunlight at 50°C.

^mInitial performance. References 24 and 25 review the stability of similar devices.

ⁿInitial efficiency. Reference 26 reviews the stability of similar devices.

[°]Spectral response and current-voltage curve reported in version 41 of these tables.

^pSpectral response and current-voltage curve reported in version 46 of these tables.

^qSpectral response and current-voltage curve reported in version 43 of these tables.

^rInitial performance. References 27 and 28 review the stability of similar devices.

^sSpectral response and current-voltage curve reported in version 55 of these tables.

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In recent years, approaches for contacting large-area solar cells during measurement have become increasingly complex. Since there is no explicit standard for the design of solar cell contacting units, in an earlier issue, we describe approaches for temporary electrical contacting of large-area solar cells both with and without busbars. To enable comparability between different contacting approaches and to clarify the corresponding measurement conditions, an unambiguous denotation was introduced and used in subsequent versions of these tables.

TABLE 2 'Notable exceptions' for single-junction cells and submodules: 'top dozen' confirmed results, not class records, measured under the global AM1.5 spectrum (1000 Wm⁻²) at 25°C (IEC 60904-3: 2008 or ASTM G-173-03 global).

	Efficiency			J _{sc}	Fill	Test centre	
Classification	(%)	Area (cm²)	V _{oc} (V)	(mA/cm ²)	factor (%)	(date)	Description
Cells (silicon)							
Si (crystalline)	25.0 ± 0.5	4.00 (da)	0.706	42.7 ^a	82.8	Sandia (3/99)	UNSW, p-type PERC ²⁹
Si (crystalline)	25.8 ± 0.5^{b}	4.008 (da)	0.7241	42.87 ^c	83.1	FhG-ISE (7/17)	FhG-ISE, n-type TOPCon ³⁰
Si (crystalline)	26.0 ± 0.5^{b}	4.015 (da)	0.7323	42.05 ^d	84.3	FhG-ISE (11/19)	FhG-ISE, p-type TOPCon
Si (crystalline)	26.7 ± 0.5	79.0 (da)	0.738	42.65 ^a	84.9	AIST (3/17)	Kaneka, n-type rear IBC ³¹
Si (crystalline)	26.1 ± 0.3^{b}	3.9857 (da)	0.7266	42.62 ^e	84.3	ISFH (2/18)	ISFH, p-type rear IBC ³²
Si (large)	24.0 ± 0.3^{f}	244.59 (t)	0.6940	41.58 ^g	83.3	ISFH (7/19)	LONGi, p-type PERC ³³
Si (large)	25.3 ± 0.4^{h}	268.0 (t)	0.7214	42.07 ⁱ	83.4	ISFH (11/21)	Jinko, n-type TOPCon ³⁴
Si (large)	26.6 ± 0.4^{j}	274.1 (t)	0.7513	41.30	85.6	ISFH (10/22)	LONGi, p-type HJT ³⁵
Si (large)	26.6 ± 0.5	179.74 (da)	0.7403	42.5 ^k	84.7	FhG-ISE (11/16)	Kaneka, n-type rear IBC ³¹
Cells (III-V)							
GalnP	22.0 ± 0.3^{b}	0.2502 (ap)	1.4695	16.63 ^l	90.2	NREL (1/19)	NREL, rear HJ, strained AllnP ³⁶
Cells (chalcogenide)							
CIGS (thin-film)	23.6 ± 0.4	0.899 (da	0.7671	38.30 ^m	80.5	FhG-ISE (1/23)	Evolar/UppsalaU ³⁷
CdTe (thin-film)	22.3 ± 0.2	0.4491 (da)	0.8985	31.69 ^m	78.9	NREL (2/23)	First Solar ³⁸
CZTSSe (thin-film)	14.9 ± 0.3	0.2694 (da)	0.5554	36.93 ^m	72.5	NPVM (4/23)	IoP/CAS ¹³
CZTS (thin-film)	11.4 ± 0.3	0.2039 (da)	0.7458	21.79 ^m	69.9	NPVM (5/23)	UNSW (Cd-free) ³⁹
Cells (other)							
Perovskite (thin-film)	26.0 ± 0.5 ^{n,o}	0.07461 (da)	1.190	26.00 ^m	84.0	JET (3/23)	loS/CAS ⁴⁰
Organic (thin-film)	19.2 ± 0.3 ^p	0.0326 (da)	0.9135	26.61 ^m	79.0	NREL (3/23)	SJTU ⁴¹
Dye sensitised	13.0 ± 0.4^{q}	0.1155 (da)	1.0396	15.55 ^m	80.4	FhG-ISE (10/20)	EPFL ⁴²

Abbreviations: (ap), aperture area; (da), designated illumination area; (t), total area; AIST, Japanese National Institute of Advanced Industrial Science and Technology; CIGS, Culn_{1-y}Ga_ySe₂; CZTS, Cu₂ZnSnS₄; CZTSSe, Cu₂ZnSnS_{4-y}Se_y; FhG-ISE, Fraunhofer-Institut für Solare Energiesysteme; ISFH, Institute for Solar Energy Research, Hamelin; NREL, National Renewable Energy Laboratory.

^aSpectral response reported in version 36 of these tables.

^bNot measured at an external laboratory.

 $^{^{\}mbox{\scriptsize c}}\mbox{Spectral}$ response and current–voltage curves reported in version 51 of these tables.

^dSpectral response and current-voltage curves reported in version 55 of these tables.

^eSpectral response and current-voltage curve reported in version 52 of these tables.

^fContacting: Front: 12BB, busbar resistance neglected; Rear: fully metallized, full area contacting.

gSpectral response and current-voltage curves reported in version 57 of these tables.

^hContacting: Front: OBB, grid resistance neglecting; Rear: 9BB, full area contacting, highly reflective chuck.

ⁱSpectral response and current-voltage curves reported in version 60 of these tables.

^jContacting: Front: busbar resistance neglecting contacting; Rear: 9BB, grid resistance neglecting contacting, gold plated chuck.

^kSpectral response and current-voltage curves reported in version 50 of these tables.

¹Spectral response and current-voltage curve reported in version 54 of these tables.

^mSpectral response and current-voltage curves reported in the present version of these tables.

ⁿStability not investigated. References 24 and 25 document stability of similar devices.

 $^{^{\}circ}$ Measured using 10-point IV sweep with constant voltage bias until current change rate <0.07%/min.

PLong-term stability not investigated. References 27 and 28 document stability of similar devices.

^qLong-term stability not investigated. Reference 26 documents stability of similar devices.

TABLE 3 Confirmed multiple-junction terrestrial cell and submodule efficiencies measured under the global AM1.5 spectrum (1000 W/ m^2) at 25°C (IEC 60904-3: 2008 or ASTM G-173-03 global).

Classification	Efficiency (%)	Area (cm²)	V _{oc} (V)	J _{sc} (mA/cm ²)	Fill factor (%)	Test centre (date)	Description
III-V multijunctions							
5 junction cell (bonded) (2.17/1.68/1.40/1.06/.73 eV)	38.8 ± 1.2	1.021 (ap)	4.767	9.564	85.2	NREL (7/13)	Spectrolab, 2-terminal
InGaP/GaAs/InGaAs	37.9 ± 1.2	1.047 (ap)	3.065	14.27 ^a	86.7	AIST (2/13)	Sharp, 2-term. ⁴³
GalnP/GaAs (monolithic)	32.8 ± 1.4	1.000 (ap)	2.568	14.56 ^b	87.7	NREL (9/17)	LG Electronics, 2-term.
III-V/Si multijunctions							
GalnP/GalnAsP/Si (bonded)	35.9 ± 1.3°	3.987 (ap)	3.248	13.11 ^d	84.3	FhG-ISE (4/20)	Fraunhofer ISE, 2-term. ⁴⁴
GalnP/GaAs/Si (mech. stack)	35.9 ± 0.5°	1.002 (da)	2.52/0.681	13.6/11.0	87.5/78.5	NREL (2/17)	NREL/CSEM/EPFL, 4-term. ⁴⁵
GalnP/GaAs/Si (monolithic)	25.9 ± 0.9 ^c	3.987 (ap)	2.647	12.21 ^e	80.2	FhG-ISE (6/20)	Fraunhofer ISE, 2-term. ⁴⁶
GaAsP/Si (monolithic)	23.4 ± 0.3	1.026 (ap)	1.732	17.34 ^f	77.7	NREL (5/20)	OSU/UNSW/SolAero, 2-term. ⁴⁷
GaAs/Si (mech. stack)	32.8 ± 0.5 ^c	1.003 (da)	1.09/0.683	28.9/11.1 ^g	85.0/79.2	NREL (12/16)	NREL/CSEM/EPFL, 4-term. ⁴⁵
GalnP/GalnAs/Ge; Si (spectral split minimodule)	34.5 ± 2.0	27.83 (ap)	2.66/0.65	13.1/9.3	85.6/79.0	NREL (4/16)	UNSW/Azur/Trina, 4-term. ⁴⁸
Perov./Si multijunctions							
Perovskite/Si	33.7 ± 1.1 ^h	1.0035 (da)	1.974	20.99 ⁱ	81.3	JRC/ESTI (5/23)	KAUST, 2-term. ⁴⁹
Perovskite/Si (large)	28.6 ± 1.4 ^h	258.14 (t)	1.909	19.11 ⁱ	78.3	FhG-ISE (5/23)	Oxford PV, 2-term. ⁵⁰
Perov.(minimod.)/Si (cell)	28.4 ± 0.7 ^h	63.98 (da)	1.21 ^j /.648	21.9 ^{ij} /14.3	78.7/81.4	AIST (1/23)	Kaneka, 4-term. ⁵¹
Other multijunctions							
Perovskite/CIGS	24.2 ± 0.7 ^h	1.045 (da)	1.768	19.24 ^f	72.9	FhG-ISE (1/20)	HZB, 2-terminal ⁵²
Perovskite/perovskite	28.2 ± 0.5 ^h	1.038 (da)	2.159	16.59 ⁱ	78.9	JET (12/22)	NanjingU/Renshine, 2-term. ⁵³
Perovskite/perovskite (minimodule)	24.5 ± 0.6 ^h	20.25 (da)	2.157	14.86 ^k	77.5	JET (6/22)	NanjingU/Renshine, 2-term. ⁵⁴
a-Si/nc-Si/nc-Si (thin-film)	$14.0 \pm 0.4^{l,c}$	1.045 (da)	1.922	9.94 ^m	73.4	AIST (5/16)	AIST, 2-term. ⁵⁵
a-Si/nc-Si (thin-film cell)	12.7 ± 0.4 ^{l,c}	1.000 (da)	1.342	13.45 ⁿ	70.2	AIST (10/14)	AIST, 2-term. ⁵⁶
'Notable exceptions'							
GaInP/GaAs (mqw)	32.9 ± 0.5 ^c	0.250 (ap)	2.500	15.36°	85.7	NREL (1/20)	NREL/UNSW, multiple QW
GalnP/GaAs/GalnAs	37.8 ± 1.4	0.998 (ap)	3.013	14.60°	85.8	NREL (1/18)	Microlink (ELO) ⁵⁷
GalnP/GaAs (mqw)/GalnAs	39.5 ± 0.5 ^c	0.242 (ap)	2.997	15.44 ^p	85.3	NREL (9/21)	NREL, multiple QW
6 junction (monolithic) (2.19/1.76/1.45/1.19/.97/ .7 eV)	39.2 ± 3.2°	0.247 (ap)	5.549	8.457 ^q	83.5	NREL (11/18)	NREL, inv. metamorphic ⁵⁸
GalnP/AlGaAs/CIGS	28.1 ± 1.2 ^c	0.1386 (da)	2.952	11.72 ^d	81.1	AIST (1/21)	AIST/FhG-ISE, 2-term. ⁵⁹
Perovskite/perovskite	29.1 ± 0.5 ^h	0.0489 (da)	2.154	16.51 ⁱ	81.7	JET (12/22)	NanjingU/Renshine, 2-term. ⁵³
Perovskite/organic	23.4 ± 0.8^{h}	0.0552 (da)	2.136	14.56 ^r	75.6	JET (3/22)	NUS/SERIS, 2-term. ⁶⁰

Abbreviations: (ap), aperture area; (da), designated illumination area; (t), total area; AIST, Japanese National Institute of Advanced Industrial Science and Technology; a-Si, amorphous silicon/hydrogen alloy; FhG-ISE, Fraunhofer Institut für Solare Energiesysteme; nc-Si, nanocrystalline or microcrystalline silicon

TABLE 4 Confirmed non-concentrating terrestrial module efficiencies measured under the global AM1.5 spectrum (1000 W/m²) at a cell temperature of 25°C (IEC 60904-3: 2008 or ASTM G-173-03 global).

Classification	Effic. (%)	Area (cm²)	V _{oc} (V)	I _{sc} (A)	FF (%)	Test centre (date)	Description
Si (crystalline)	24.7 ± 0.3	17,806 (da)	83.04	6.384 ^a	82.9	NREL (4/23)	Maxeon (112 cells)
Si (multicrystalline)	20.4 ± 0.3	14,818 (ap)	39.90	9.833 ^b	77.2	FhG-ISE (10/19)	Hanwha Q Cells (60 cells) ⁶¹
GaAs (thin-film)	25.1 ± 0.8	866.45 (ap)	11.08	2.303 ^c	85.3	FhG-ISE (11/17)	Alta Devices ⁶²
CIGS (Cd-free)	19.2 ± 0.5	841 (ap)	48.0	0.456 ^c	73.7	AIST (1/17)	Solar Frontier (70 cells) ⁶³
CdTe (thin-film)	19.5 ± 1.4	23,582 (da)	227.9	2.622 ^d	76.8	NREL (9/21)	First Solar ⁶⁴
a-Si/nc-Si (tandem)	12.3 ± 0.3 ^e	14,322 (t)	280.1	0.902 ^f	69.9	ESTI (9/14)	TEL Solar, Trubbach Labs ⁶⁵
Perovskite	18.6 ± 0.7 ^g	809.9 (da)	44.7	0.479 ^a	70.3	JET (5/23)	UtmoLight (39 cells) ⁶⁶
Organic	13.1 ± 0.3 ^h	1,475.0 (da)	48.10	0.6015 ^a	67.8	NREL (5/23)	Ways/Nanobit ⁶⁷
Multijunction							
InGaP/GaAs/InGaAs	32.65 ± 0.7	965 (da)	24.30	1.520 ^d	85.3	AIST (2/22)	Sharp (40 cells; 8 series) ⁶⁸
'Notable Exceptions'							
CIGS (large)	18.6 ± 0.6	10,858 (ap)	58.00	4.545 ^b	76.8	FhG-ISE (10/19)	Miasole ⁶⁹
InGaP/GaAs//Si	33.7 ± 0.7	775 (da)	20.3/2.83	1.25/1.93 ^a	86.5/78.0	AIST (2/23)	Sharp, 4-term. ⁷⁰
InGaP/GaAs//CIGS	31.2 ± 0.7	778 (ap)	20.3/16.9	1.24/.26 ^a	85.7/59.8	AIST (2/23)	Sharp, 4-term. ⁷⁰

Abbreviations: (ap), aperture area; (da), designated illumination area; (t), total area; a-Si, amorphous silicon/hydrogen alloy; a-SiGe, amorphous silicon/germanium/hydrogen alloy; CIGSS, CulnGaSSe; Effic, efficiency; FF, fill factor; nc-Si, nanocrystalline or microcrystalline silicon.

Tabled results are reported for cells and modules made from different semiconductors and for sub-categories within each semiconductor grouping (e.g., crystalline, polycrystalline or directionally solidified and thin film). From version 36 onwards, spectral response information is included (when possible) in the form of a plot of the external quantum efficiency (EQE) versus wavelength, either as

^aSpectral response and current-voltage curve reported in version 42 of these tables.

^bSpectral response and current-voltage curve reported in the version 51 of these tables.

^cNot measured at an external laboratory.

^dSpectral response and current-voltage curve reported in version 58 of these tables.

^eSpectral response and current-voltage curve reported in version 57 of these tables.

^fSpectral response and current-voltage curve reported in version 56 of these tables.

^gSpectral response and current-voltage curve reported in version 52 of these tables.

^hInitial efficiency. References 24 and 25 review the stability of similar perovskite-based devices. ⁱSpectral response and current-voltage curves reported in the present version of these tables.

^jReported on a 'per cell' basis.

^kSpectral response and current-voltage curve reported in version 61 of these tables.

Stabilised by 1000-h exposure to 1 sunlight at 50°C.

^mSpectral response and current-voltage curve reported in version 49 of these tables.

ⁿSpectral responses and current-voltage curve reported in version 45 of these tables.

[°]Spectral response and current-voltage curve reported in version 53 of these tables.

^pSpectral response and current-voltage curves reported in version 59 of these tables.

 $^{{}^{\}rm q}{\rm Spectral}$ response and current-voltage curve reported in version 54 of these tables.

^rSpectral response and current-voltage curve reported in version 60 of these tables.

^aSpectral response and current-voltage curve reported in the present version of these tables.

^bSpectral response and current-voltage curve reported in version 55 of these tables.

^cSpectral response and current-voltage curve reported in version 50 or 51 of these tables.

^dSpectral response and current-voltage curve reported in version 60 of these tables.

eStabilised at the manufacturer to the 2% level following IEC procedure of repeated measurements.

^fSpectral response and/or current-voltage curve reported in version 46 of these tables.

^gInitial performance. References 25 and 26 review the stability of similar devices.

^hInitial performance. References 28 and 29 review the stability of similar devices.

TABLE 5 Terrestrial concentrator cell and module efficiencies measured under the ASTM G-173-03 direct beam AM1.5 spectrum at a cell temperature of 25°C (except where noted for the hybrid and luminescent modules).

Classification	Effic. (%)	Area (cm²)	Intensity ^a (suns)	Test centre (date)	Description
Single cells					
GaAs	30.8 ± 1.9 ^{b,c}	0.0990 (da)	61	NREL (1/22)	NREL, 1 junction (1J)
Si	27.6 ± 1.2^{d}	1.00 (da)	92	FhG-ISE (11/04)	Amonix back-contact ⁷¹
CIGS (thin-film)	$23.3 \pm 1.2^{b,e}$	0.09902 (ap)	15	NREL (3/14)	NREL ⁷²
Multijunction cells					
AlGalnP/AlGaAs/GaAs/GalnAs(3) (2.15/1.72/1.41/1.17/0.96/0.70 eV)	47.1 ± 2.6 ^{b,f}	0.099 (da)	143	NREL (3/19)	NREL, 6J inv. metamorphic ⁵⁸
GalnP/GalnAs; GalnAsP/GalnAs	$47.6 \pm 2.6^{b,g}$	0.0452 (da)	665	FhG-ISE (5/22)	FhG-ISE 4J bonded ⁷³
GalnP/GaAs/GalnAs/GalnAs	$45.7 \pm 2.3^{b,h}$	0.09709 (da)	234	NREL (9/14)	NREL, 4J monolithic ⁷⁴
InGaP/GaAs/InGaAs	44.4 ± 2.6^{i}	0.1652 (da)	302	FhG-ISE (4/13)	Sharp, 3J inverted metamorphic ⁷⁵
GalnAsP/GalnAs	$35.5 \pm 1.2^{b,j}$	0.10031 (da)	38	NREL (10/17)	NREL 2-junction (2 J) ⁷⁶
Minimodule					
GalnP/GaAs; GalnAsP/GalnAs	$43.4 \pm 2.4^{b,k}$	18.2 (ap)	340 ^l	FhG-ISE (7/15)	Fraunhofer ISE 4J (lens/cell) ⁷⁷
Submodule					
GalnP/GalnAs/Ge; Si	40.6 ± 2.0^{k}	287 (ap)	365	NREL (4/16)	UNSW 4J split spectrum ⁷⁸
Modules					
Si	20.5 ± 0.8^{b}	1875 (ap)	79	Sandia (4/89) ^l	Sandia/UNSW/ENTECH (12 cells) ⁷⁹
Three junction (3J)	35.9 ± 1.8^{m}	1,092 (ap)	N/A	NREL (8/13)	Amonix ⁸⁰
Four junction (4J)	38.9 ± 2.5 ⁿ	812.3 (ap)	333	FhG-ISE (4/15)	Soitec ⁸¹
Hybrid module ^o					
4-Junction (4J)/bifacial c-Si	$34.2 \pm 1.9^{b,o}$	1,088 (ap)	CPV/PV	FhG-ISE (9/19)	FhG-ISE (48/8 cells; 4T)82
'Notable exceptions'					
Si (large area)	21.7 ± 0.7	20.0 (da)	11	Sandia (9/90) ^l	UNSW laser grooved ⁸³
Luminescent Minimodule ^o	7.1 ± 0.2	25 (ap)	2.5 ^p	ESTI (9/08)	ECN Petten, GaAs cells ⁸⁴
4J Minimodule	41.4 ± 2.6^{b}	121.8 (ap)	230	FhG-ISE (9/18)	FhG-ISE, 10 cells ⁸⁵

Note: Following the normal convention, efficiencies calculated under this direct beam spectrum neglect the diffuse sunlight component that would accompany this direct spectrum. These direct beam efficiencies need to be multiplied by a factor estimated as 0.8746 to convert to thermodynamic efficiencies. 86

Abbreviations: (ap), aperture area; (da), designated illumination area; CIGS, CulnGaSe₂; Effic, efficiency; FhG-ISE, Fraunhofer-Institut für Solare Energiesysteme; NREL, National Renewable Energy Laboratory.

4-terminal module with external dual-axis tracking. Power rating of CPV follows IEC 62670-3 standard, front power rating of flat plate PV based on IEC 60904-3, -5, -7, -10 and 60891 with modified current translation approach; rear power rating of flat plate PV based on IEC TS 60904-1-2 and 60891.

PGeometric concentration.

^aOne sun corresponds to direct irradiance of 1000 Wm⁻².

^bNot measured at an external laboratory.

^cSpectral response and current-voltage curve reported in version 60 of these tables.

^dMeasured under a low aerosol optical depth spectrum similar to ASTM G-173-03 direct.⁸⁷

eSpectral response and current-voltage curve reported in version 44 of these tables.

^fSpectral response and current-voltage curve reported in version 54 of these tables.

gSpectral response and current-voltage curve reported in version 61 of these tables.

^hSpectral response and current-voltage curve reported in version 46 of these tables.

ⁱSpectral response and current-voltage curve reported in version 42 of these tables.

Spectral response and current–voltage curve reported in version 51 of these tables.

^kDetermined at IEC 62670-1 CSTC reference conditions.

^IRecalibrated from original measurement.

^mReferenced to 1000-W/m² direct irradiance and 25°C cell temperature using the prevailing solar spectrum and an in-house procedure for temperature translation.

ⁿMeasured under IEC 62670-1 reference conditions following the current IEC power rating draft 62670-3.

 $^{^{\}circ}$ Thermodynamic efficiency. Hybrid and luminescent modules measured under the ASTM G-173-03 or IEC 60904-3: 2008 global AM1.5 spectrum at a cell temperature of 25 $^{\circ}$ C.

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absolute values or normalised to the peak measured value. Current-voltage (IV) curves have also been included where possible from version 38 onwards.

The highest confirmed 'one sun' cell and module results are reported in Tables 1–4. Any changes in the tables from those previously published are set in bold type. In most cases, a literature reference is provided that describes either the result reported, or a similar result (readers identifying improved references are welcome to submit to the lead author). Table 1 summarises the best-reported measurements for 'one-sun' (non-concentrator) single-junction cells and submodules.

Table 2 contains what might be described as 'notable exceptions' for 'one-sun' single-junction cells and submodules in the above

category. While not conforming to the requirements to be recognised as a class record, the devices in Table 2 have notable characteristics that will be of interest to sections of the photovoltaic community, with entries based on their significance and timeliness. To encourage discrimination, the table is limited to nominally 12 entries with the present authors having voted for their preferences for inclusion. Readers who have suggestions of notable exceptions for inclusion into this or subsequent tables are welcome to contact any of the authors with full details. Suggestions conforming to the guidelines will be included on the voting list for a future issue.

Table 3 was first introduced in version 49 of these tables and summarises the growing number of cell and submodule results involving high efficiency, one-sun multiple-junction devices (previously

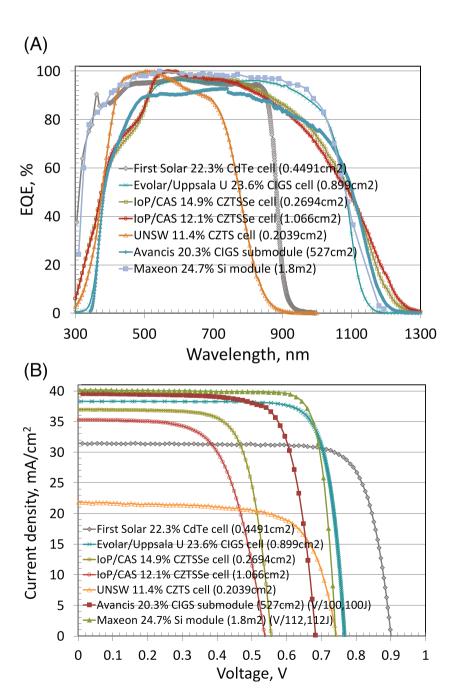


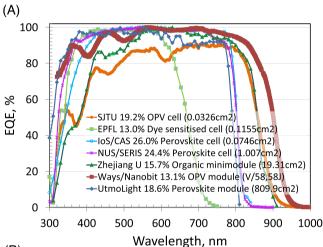
FIGURE 1 (A) External quantum efficiency (EQE) for the new chalcogenide thin-film and silicon cell and module results reported in this issue (most results are normalised).

(B) Corresponding current density-voltage (JV) curves.

reported in Table 1). Table 4 shows the best results for one-sun modules, both single- and multiple-junction, while Table 5 shows the best results for concentrator cells and concentrator modules. A small number of 'notable exceptions' are also included in Tables 3 to 5.

2 | NEW RESULTS

Twenty-one new results are reported in the present version of these tables. The first new result in Table 1 ('one-sun cells and submodules') is the increase in efficiency to 20.3% for a large (527 cm²) Culn_{1-x}Ga_x-S_ySe_{2-y} (CIGSSe) submodule fabricated by Avancis¹¹ and measured by the US National Renewable Energy Laboratory (NREL). The second new result is 12.1% aperture area efficiency for a 1-cm² Cu₂ZnSnS_y-Se_{4-y} (CZTSSe) cell¹³ fabricated by the Institute of Physics, Chinese Academy of Sciences (IoP/CAS) and measured by the Chinese National Photovoltaic Industry Measurement and Testing Center



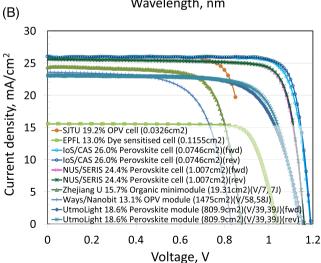
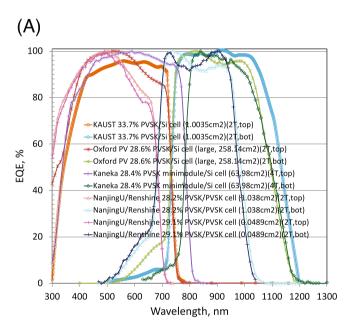


FIGURE 2 (A) External quantum efficiency (EQE) for the new perovskite, organic and dye-sensitised thin-film cell and module results reported in this issue (most results are normalised).

(B) Corresponding current density-voltage (JV) curves.

(NPVM). The third new result is 24.35% efficiency for a 1-cm² perovskite cell¹¹ fabricated by the National University of Singapore (NUS) in conjunction with the Solar Energy Research Institute of Singapore (SERIS) and again measured by NPVM. The final new result in Table 1 is 15.7% efficiency for a 19-cm² organic photovoltaic (OPV) minimodule²² fabricated by Zhejiang University in collaboration with EnrichPV and Microquanta and measured by the Japan Electrical Safety and Environment Technology Laboratories (JET).

There are seven new results in Table 2 (one-sun 'notable exceptions'), all involving small area, thin-film solar cells. The first is an efficiency of 23.6% for a 0.9-cm² Culn_{1-x}Ga_xSe₂ (CIGS) cell fabricated in a collaboration between Evolar and Uppsala University³⁷ and measured by the Fraunhofer Institute for Solar Energy Systems (FhG-ISE).



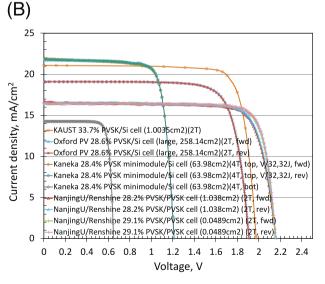


FIGURE 3 (A) External quantum efficiency (EQE) for the new multijunction cell results reported in this issue (most results are normalised). (B) Corresponding current density-voltage (JV) curves.

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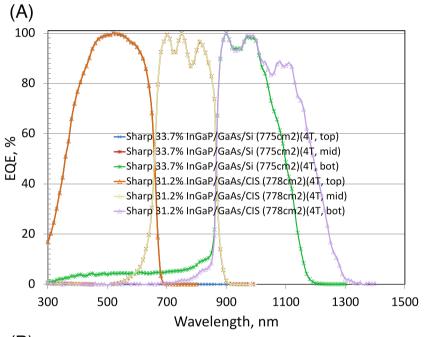
al University Of Kyiv, Wiley Online Library on [25/03/2024].

This cell is only slightly too small to be included in Table 1 as an outright record. The second new result is 22.3% for a smaller 0.4-cm² CdTe cell fabricated by First Solar³⁸ and measured by NREL, displacing one of the table's longest lasting results, a 22.1% cell¹ also fabricated by First Solar in 2015.

The third new result reports a massive improvement in the performance of a CZTSSe cell to 14.9% for a 0.3-cm² device fabricated by IoP/CAS 13 and measured by NPVM. The fourth describes an increase in efficiency to 11.4% for pure sulfide, Cd-free, 'earth abundant' $\rm Cu_2ZnSnS_4$ (CZTS) for a 0.2-cm² Cd-free device fabricated by the University of New South Wales, Sydney (UNSW) 39 and again measured by NPVM.

The final three new results in Table 2 relate to the popular perovskite, organic and dye-sensitised cells. An efficiency of 26.0% was measured by JET for a very small 0.07-cm² perovskite cell fabricated by the Institute of Semiconductors, Chinese Academy of Sciences (IoS/CAS).⁴⁰ An even smaller 0.03-cm² organic cell fabricated by Shanghai Jiao Tong University (SJTU) was measured to have 19.2% efficiency⁴¹ by NREL. An earlier result previously overlooked was 13.0% efficiency for a 0.1-cm² dye-sensitised cell fabricated by Ecole Polytechnique Fédérale de Lausanne (EPFL)⁴² and measured by the Fraunhofer Institute for Solar Energy Systems (FhG-ISE).

This brings us to Table 3, multijunction cells. Accurate measurements of the performance of such cells under standardised test conditions pose additional challenges compared with the case of single junction cells. In particular, for series-connected cells, it is important to have the same current balance between the cells as would occur under the reference spectrum. Standards define a current balance or



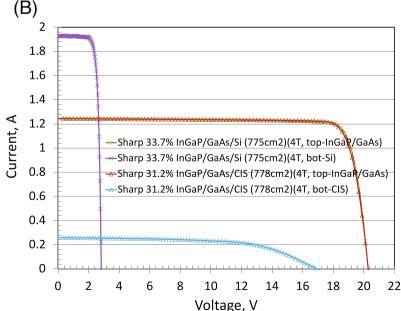


FIGURE 4 (A) External quantum efficiency (EQE) for the new module results reported in this issue (all results are normalised). (B) Corresponding current density-voltage (JV) curves.

matching factor, Z, that estimates how well this is likely to be achieved for each cell under test conditions. Although $Z=1.00\pm0.03$ is regarded as acceptable, the standards encourage striving for $Z=1.00\pm0.01$ to maintain the highest quality of data reported. Our designated test centres have agreed that the tables will only accept results within $Z=1.00\pm0.01$ for the matching factors of multijunction cells in the future, and each will report on Z values when submitting multijunction results.

In the present case, we have five new entries in Table 3, all involving at least one perovskite cell. The first new result is for a 1-cm² 2-terminal perovskite/silicon tandem cell where there has been remarkable progress since the previous issue of these tables. In that issue, a new record of 31.3% was reported for a cell fabricated by EPFL PVLAB/CSEM and measured by NREL in June 2022, the first to exceed the 30% milestone. This was followed by a 32.5% result later in 2022 for a cell fabricated by Helmholtz-Zentrum Berlin and confirmed by the European Solar Test Installation (ESTI). In March 2023, both ESTI and JET confirmed 33.2% and 33.3%, respectively, for two cells from the same batch fabricated by the King Abdullah University of Science and Technology (KAUST), Saudi Arabia. In May 2023, ESTI confirmed 33.7% efficiency for a cell again fabricated by KAUST. ⁴⁹ This is higher in efficiency than any other two-cell tandem in the tables.

Also in May, an efficiency of 28.6% was confirmed by FhG-ISE for a much larger 258-cm² 2-terminal perovskite/silicon tandem cell fabricated by Oxford PV.⁵⁰ Good results are also reported for a 64-cm² 4-terminal tandem fabricated by Kaneka,⁵¹ consisting of a 32-cell perovskite minimodule mechanically stacked onto a single silicon cell. A combined efficiency of 28.4% was measured by the Japanese National Institute of Advanced Industrial Science and Technology (AIST).

The two remaining new results in Table 3 involve a tandem stack of two perovskite cells of different compositions, with both devices fabricated by Nanjing University in collaboration with Renshine Solar (Suzhou) Co. Ltd and both measured by JET. The first is 28.2% efficiency for a 1-cm² device, 53 suggesting the 30% milestone is also within reach for this approach, while the second is 29.1% for a much smaller 0.05-cm² device. 53

The final five new results in this issue are in Table 4 (one-sun modules). The first reports an increase in efficiency to 24.7% for a large area (1.8 m²), monocrystalline silicon module fabricated by Maxeon and measured by NREL. The second reports an efficiency increase to 18.6% for a smaller (810 cm²) perovskite module fabricated by UtmoLight and measured by JET, while the third reports a substantial increase in efficiency to 13.1% for a larger (1,475 cm²) module fabricated by Ways Technical Coprporation in conjunction with Nanobit and measured by NREL.

The final two results report two high-efficiency 4-terminal modules fabricated by Sharp and measured by AIST that consist of a III–V tandem cell module mechanically stacked on a silicon module in the first case and a CIGS module in the second case.⁷⁰ These are listed as 'notable exceptions' since both are slightly below the Table's 800-cm² requirement for classification as a module. The combined

efficiency is 33.7% in the first case and 31.2% in the second, suggesting the type of commercial performance the industry might see in the future.

The EQE spectra for the new chalcogenide thin-film and silicon cells and modules reported in the present issue of these tables are shown in Figure 1A, with Figure 1B showing the current density-voltage (JV) curves for the same devices. Figure 2A,B shows the corresponding EQE and JV curves for the new perovskite, organic and dyesensitised thin-film cell and module results. Figure 3A,B shows these for the new multijunction cell results, while Figure 4A,B shows these for the new 4-terminal multijunction module results.

3 | DISCLAIMER

While the information provided in the tables is provided in good faith, the authors, editors and publishers cannot accept direct responsibility for any errors or omissions.

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DATA AVAILABILITY STATEMENT

The data that support the findings of this study are available from the corresponding author upon reasonable request.

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APPENDIX A: LIST OF DESIGNATED TEST CENTRES

A list of designated test centres can be found in version 61.¹ An additional designated test centre not there listed is:

Newport PV Lab

3050 North 300 West, North Logan, UT 84341, USA.

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(Terrestrial cells)